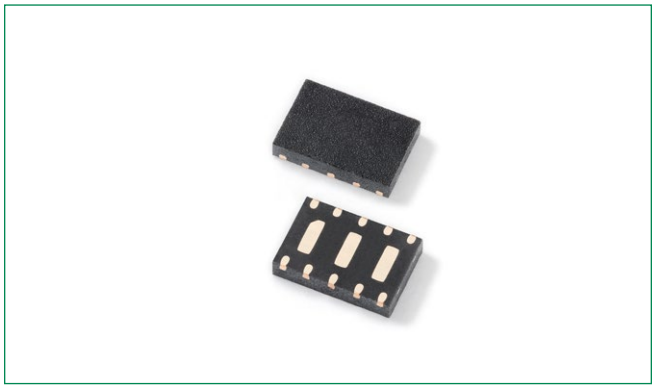
SP3374NUTG 3.3V 40A Diode Array

RoHS Pb GREEN

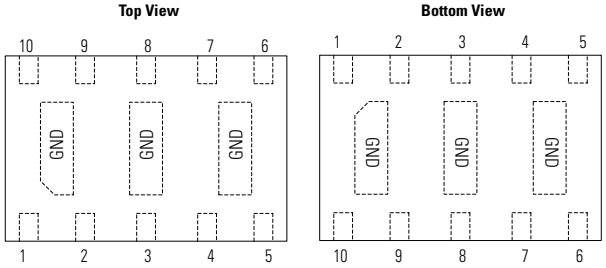


Description

The SP3374NUTG is a low-capacitance, TVS Diode Array designed to provide protection against ESD (electrostatic discharge), CDE (cable discharge events), EFT (electrical fast transients), and lightning induced surges for high-speed, differential data lines. It's packaged in a µDFN package (3.0 x 2.0mm) and each device can protect up 4 channels or 2 differential pairs, up to 40A (IEC 61000-4-5 2nd edition,) and up to 30kV ESD (IEC 61000-4-2). The "flow-through" design minimizes signal distortion, reduces voltage overshoot, and provides a simplified PCB design.

The SP3374NUTG with its low capacitance and low clamping voltage makes it ideal for high-speed data interfaces such as 1GbE applications found in notebooks, switches, etc.

Pinout

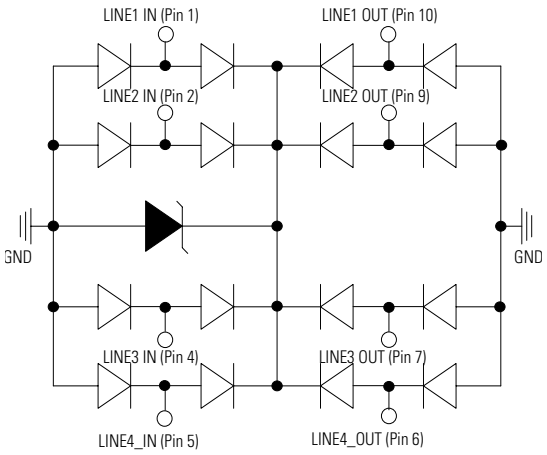


NOTE: PIN3, PIN8 are same potential with GND

Features

- ESD, IEC 61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC 61000-4-4, 40A (5/50ns)
- Lightning, 40A (8/20µs as defined in IEC 61000-4-5 2nd Edition)
- Low capacitance of 3.5pF@0V (TYP) per I/O
- Low leakage current of 0.1µA (TYP) at 3.3V
- µDFN-10 package is optimized for high-speed data line routing
- Provides protection for two differential data pairs (4 channels) up to 40A
- Low operating and clamping voltage
- AEC-Q101 qualified
- Halogen free, Lead free and RoHS compliant

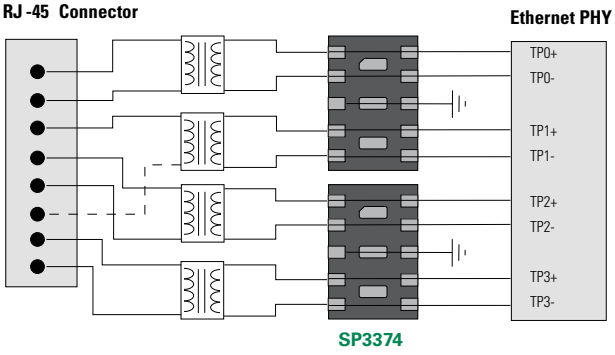
Functional Block Diagram



Applications

- 10/100/1000 Ethernet
- WAN/LAN Equipment
- Desktops, Servers and Notebooks
- LVDS Interfaces
- Integrated Magnetics
- Smart TV

Application Example



Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

Revised: 09/13/19

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I_{PP}	Peak Current (t_p=8/20µs)	40	A
P_{Pk}	Peak Pulse Power (t_p=8/20µs)	1000	W
T_{OP}	Operating Temperature	-40 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

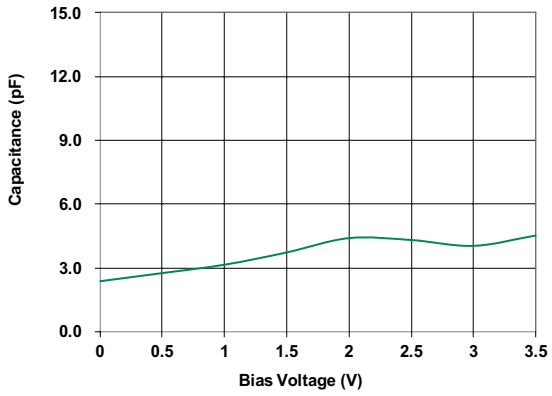
Electrical Characteristics (T_{OP}=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1\mu A$			3.3	V
Reverse Leakage Current	I_R	V_{RWM} = 3.3V, T = 25°C		0.1	0.5	µA
Snap Back Voltage	V_{SB}	I_{SB} = 50mA	2.8			V
Clamp Voltage	V_C	I_{PP} = 1A, t_p = 8/20µs Any I/O to Ground			5.5	V
		I_{PP} = 10A, t_p = 8/20µs Any I/O to Ground			10.5	
		I_{PP} = 25A, t_p = 8/20µs Any I/O to Ground			18.0	
		I_{PP} = 40A, t_p = 8/20µs Line-to-Line[1], two I/O Pins connected together on each line			25.0	
Dynamic Resistance[2]	R_{DYN}	TLP, t_p=100ns, Any I/O to Ground		0.15		Ω
ESD Withstand Voltage	V_{ESD}	IEC 61000-4-2 (Contact)	±30			kV
		IEC 61000-4-2 (Air)	±30			kV
Diode Capacitance	$C_{I/O\ to\ GND}$	Between I/O Pins and Ground V_R = 0V, f = 1MHz		3.5	5.0	pF
	$C_{I/O\ to\ I/O}$	Between I/O Pins V_R = 0V, f = 1MHz		1.7		pF

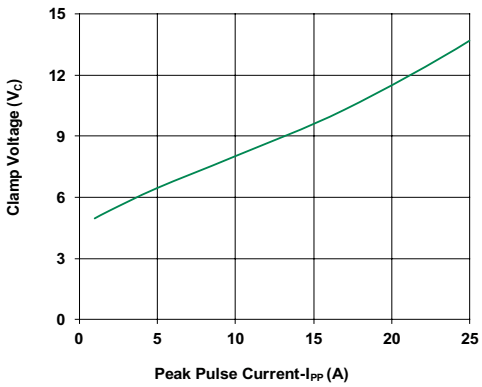
Notes:
1. Rating with 2 pins connected together per sugguested diagram (For example, pin1 is connected to pin 10, pin 2 is connected to Pin 9, Pin 4 is connected to pin 7 and pin 5 is connected to pin 6)
2. Transmission Line Pulse (TLP) with 100ns width, 2ns rise time, and average window t1=70ns to t2= 90ns

Revised: 09/13/19

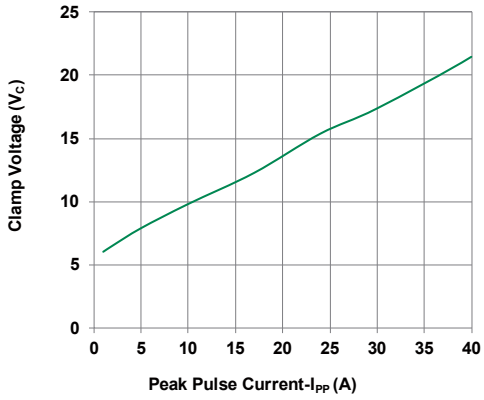
Capacitance vs. Reverse Bias



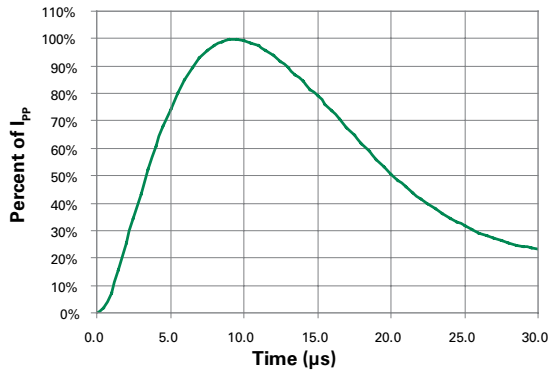
Clamping Voltage vs. I_{PP} (I/O to GND)



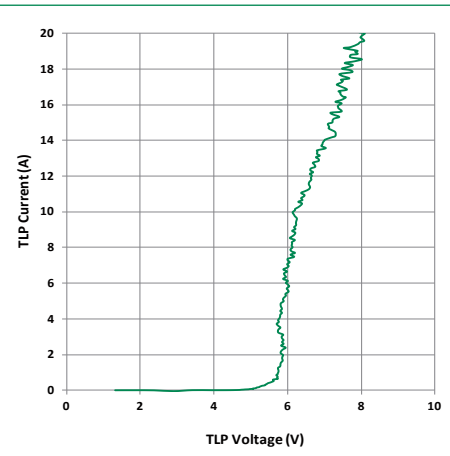
Clamping Voltage vs. I_{PP} (Line-to-Line)



8/20µS Pulse Waveform



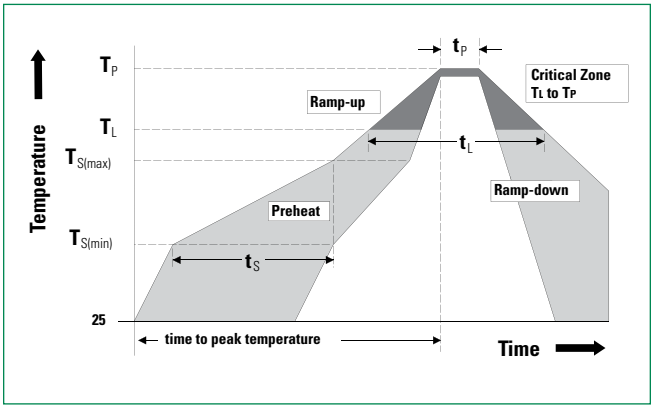
Transmission Line Pulsing(TLP) Plot



Revised: 09/13/19

Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	**- Temperature Min ($T_{s(min)}$)**	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{S(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	**- Temperature (T_L) (Liquidus)**	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		$260^{+0/-5}$ °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



Ordering Information

Part Number	Package	Min. Order Qty.
SP3374NUTG	µDFN-10 (3.0x2.0mm)	3000

Product Characteristics

Lead Plating	Pre-Plated Frame
Lead Material	Copper Alloy
Substrate material	Silicon
Body Material	Molded Compound
Flammability	UL Recognized compound meeting flammability rating V-0

Part Numbering System

SP 3374N U T G

TVS Diode Arrays
(SPA® Diodes)
Series

G= Green

T= Tape & Reel

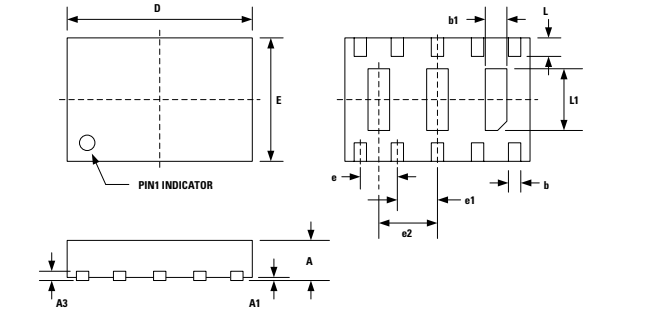
Package
µDFN-10 (3.0x2.0mm)

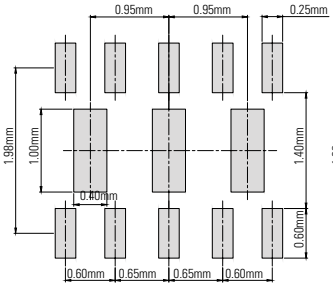
Part Marking System

bG4

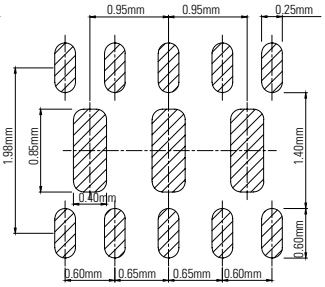
Revised: 09/13/19

Package Dimensions — µDFN-10 (3.0x2.0mm)





Recommended Soldering Pads Layout

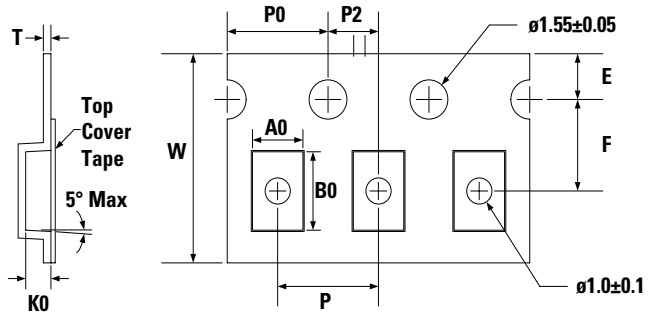


Recommended Stencil Apertures
Recommended Stencil thickness 5mils

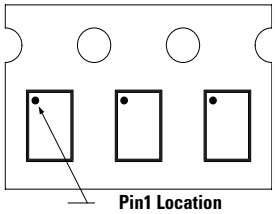
Package	µDFN-10 (3.0x2.0mm)					
JEDEC	MO-229					
Symbol	Millimeters			Inches		
	Min	Nom	Max	Min	Nom	Max
A	0.50	0.60	0.65	0.020	0.024	0.026
A1	0.00	0.03	0.05	0.000	0.001	0.002
A3		0.15 Ref			0.006 Ref	
b	0.15	0.20	0.25	0.006	0.008	0.010
b1	0.25	0.35	0.45	0.010	0.014	0.018
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.90	2.00	2.10	0.075	0.079	0.083
e		0.60 BSC			0.024 BSC	
e1		0.65 BSC			0.026 BSC	
e2		0.95 BSC			0.037	
L	0.25	0.30	0.35	0.010	0.012	0.014
L1	0.95	1.00	1.05	0.037	0.039	0.041

Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

Tape & Reel Specification — µDFN-10 (3.0x2.0mm)



Device Orientation in Tape



Package	µDFN-10 (3.0x2.0mm)
Symbol	Millimeters
A0	2.30 +/- 0.10
B0	3.20 +/- 0.10
E	1.75 +/- 0.10
F	3.50 +/- 0.05
K0	1.0 +/- 0.10
P	4.00 +/- 0.10
P0	4.00 +/- 0.10
P2	2.00 +/- 0.10
T	0.3 +/- 0.05
W	8.00 +0.30/- 0.10